

Features

- Fast response time
- High analytic
- High sensitivity
- Cut-off visible wavelength $\lambda_p=940\text{nm}$
- Pb free
- This product itself will remain within RoHS compliant version.

Descriptions

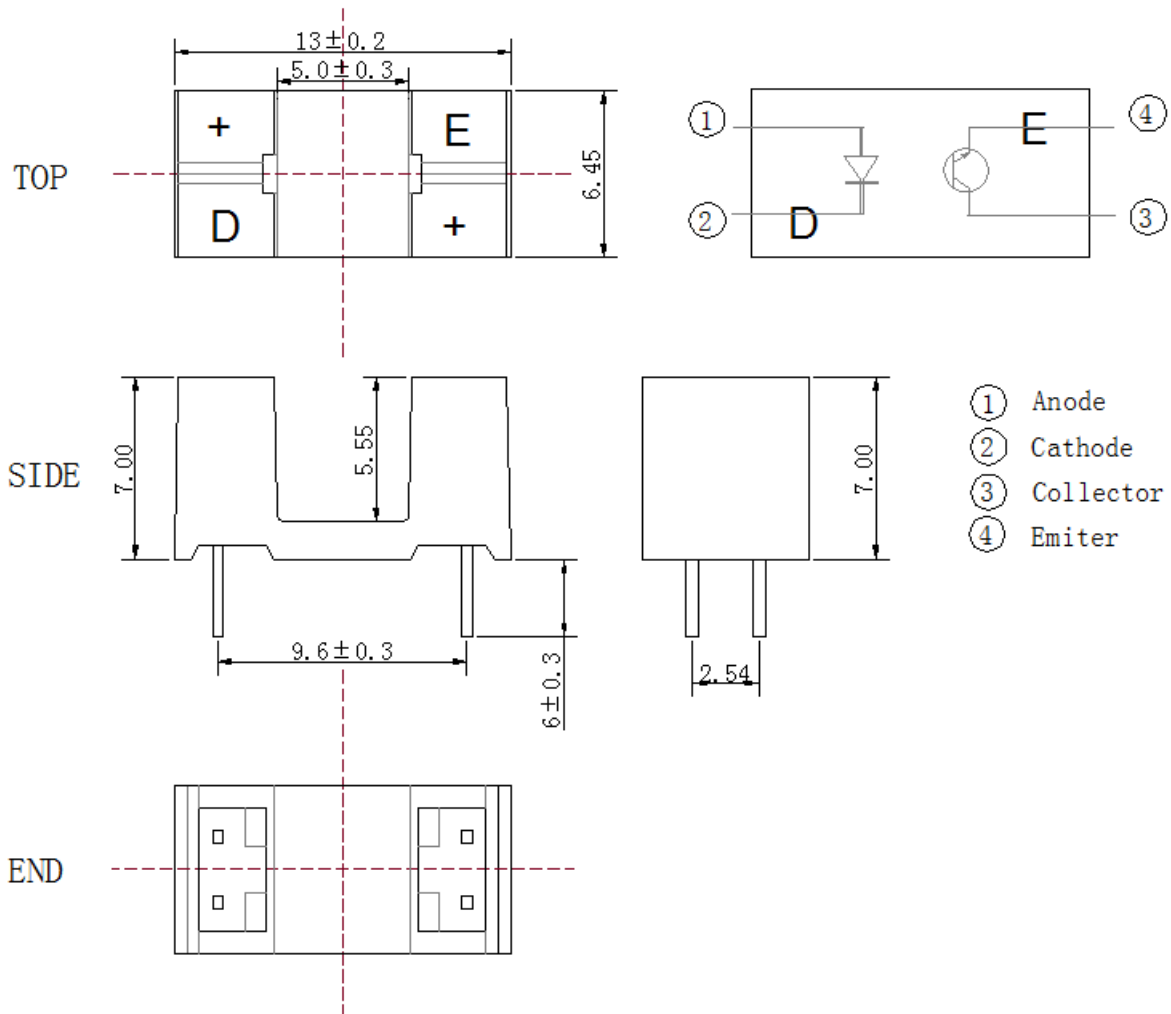
- The ITR180 consist of an infrared emitting diode and an NPN silicon phototransistor, encased side-by-side on converging optical axis in a black thermoplastic housing.
- The phototransistor receives radiation from the IRED only .This is the normal situation.
- But when an object is in between , phototransistor could not receives the radiation.

Applications

- Mouse Copier
- Switch Scanner
- Floppy disk driver
- Non-contact Switching
- For Direct Board



Package Dimensions



1.All dimensions are in millimeters

2.Tolerances unless dimensions ± 0.3 mm

3.Lead spacing is measured where the lead emerge from the package



Opto Interrupter

CGX-ITR180

Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Ratings	Unit
Input	Power Dissipation at(or below) 25°C Free Air Temperature	Pd	75	mW
	Reverse Voltage	V _R	5	V
	Forward Current	I _F	50	mA
	Peak Forward Current (*1) Pulse width ≤ 100 μs, Duty cycle=1%	I _{FP}	1	A
Output	Collector Power Dissipation	P _C	75	mW
	Collector Current	I _C	20	mA
	Collector-Emitter Voltage	B V _{CEO}	30	V
	Emitter-Collector Voltage	B V _{ECO}	5	V
Operating Temperature		Topr	-40~+85	°C
Storage Temperature		Tstg	-40~+85	°C
Lead Soldering Temperature (*2) (1/16 inch form body for 5 seconds)		Tsol	260	°C

(*1) tw=100 μsec., T=10 msec. (*2) t=5 Sec

Electro-Optical Characteristics (Ta=25°C)

Parameter		Symbol	Min.	Typ.	Max.	Unit	Condition
Input	Forward Voltage	V _F	-	1.2	1.5	V	I _F =20mA
	Reverse Current	I _R	-	-	10	μA	V _R =5V
	Peak Wavelength	λ _P	-	940	-	nm	I _F =20mA
	View Angle	2θ 1/2	-	30	-	Deg	I _F =20mA
Output	Dark Current	I _{CEO}	-	-	100	nA	V _{CE} =20V, Ee=0mW/cm ²
	C-E Saturation Voltage	V _{CE(sat)}	-	-	0.4	V	I _C =0.04mA, I _F =40mA
Collector Current		I _{C(ON)}	1.0	-	-	mA	V _{CE} =5V, I _F =5mA
Response Time	Rise Time	t _R	-	15	-	μs	V _{CE} =5V, I _C =100 μA , R _L =100Ω
	Fall Time	t _F	-	15	-	μs	

Typical Electrical/Optical/Characteristics Curves for IR

Fig. 1 Forward Current vs. Ambient Temperature

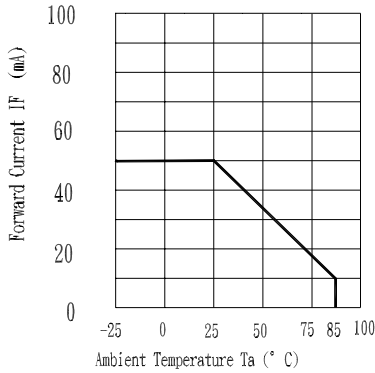


Fig. 2 Spectral Distribution

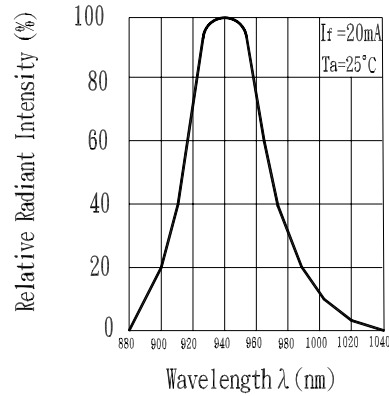


Fig. 3 Peak Emission Wavelength vs. Ambient Temperature

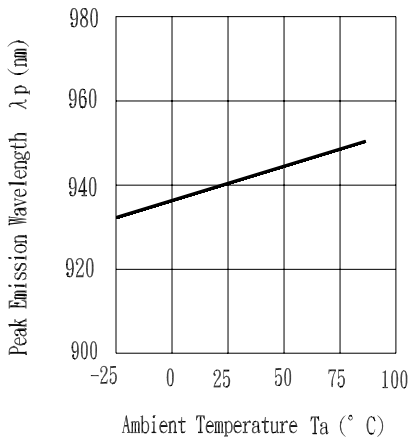


Fig. 4 Forward Current vs. Forward Voltage

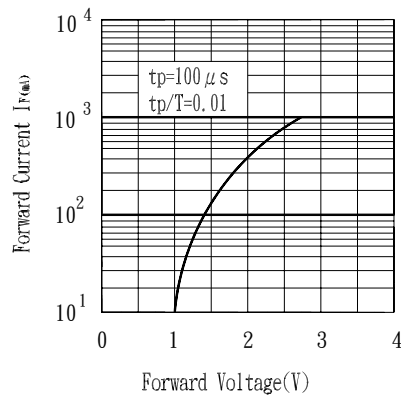


Fig. 5 Relative Intensity vs. Forward Current

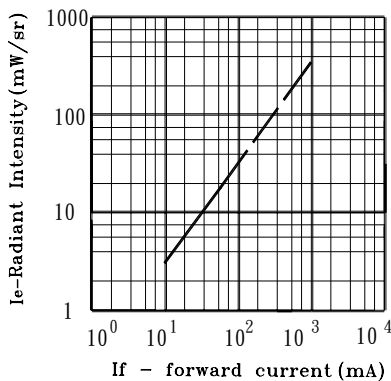
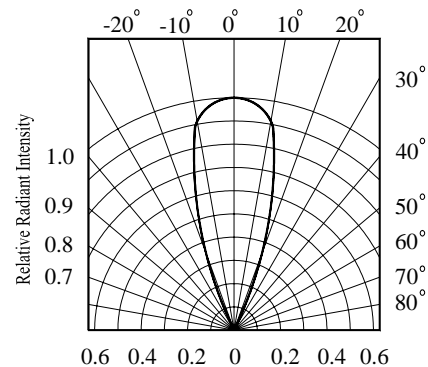


Fig. 6 Relative Radiant Intensity vs. Angular Displacement



Typical Electrical/Optical/Characteristics Curves for PT

